

- “LVDT” means Linear Voltage Differential Transformer; (LVDT)
- “MOS DRAM” means Metal Oxide Semiconductor Dynamic Random Access Memory; (MOS DRAM)
- “MOS SRAM” means Metal Oxide Semiconductor Static Random Access Memory; (MOS SRAM)
- “MTI” means Moving Target Indicator; (MTI)
- “NMOS” means Negative-Channel-Type Metal Oxide Semiconductor; (NMOS)
- “OCR” means Optical Character Recognition Equipment; (OCR)
- “OIR” means the *Organisation internationale de radiodiffusion*; (OIR)
- “OMR” means Optical Mark Recognition Equipment; (OMR)
- “PABX” means Private Automatic Branch Exchange; (PABX)
- “PCM” means Pulse Code Modulation; (PCM)
- “PIN” means P-Type Intrinsic N-Type, or Positive-Intrinsic-Negative; (PIN)
- “PIO” means Parallel Input and Output Controller; (PIO)
- “PMOS” means Positive-Channel-Type Metal Oxide Semiconductor; (PMOS)
- “PROM” means Programmable Read-Only Memory; (PROM)
- “QFM” means Quantized Frequency Modulation; (*Version anglaise seulement*)
- “RAM” means Random Access Memory; (RAM)
- “RBEC” means Roller Bearing Engineering Committee of the Anti-friction Bearing Manufacturers Association; (RBEC)
- “RF” means Radio Frequency; (*Version anglaise seulement*)
- “ROM” means Read-Only Memory; (ROM)
- “SAE” means Society of Automotive Engineers; (SAE)
- “SC” means Stress Compensated; (*Version anglaise seulement*)
- “SIO” means Serial Input and Output Controller; (SIO)
- “SQUID” means Superconducting Quantum Interference Device; (*Version anglaise seulement*)
- “SSB” means Single Side Band; (SSB)
- “TCXO” means Temperature Compensated Crystal Oscillator; (TCXO)
- “TED” means Transferred Electron Device; (TED)
- “TEM” means Transverse Electromagnetic Mode; (*Version anglaise seulement*)
- “TIR” means Total Indicator Reading; (TIR)
- “TR” means Transmit and Receive; (*Version anglaise seulement*)
- “TRANSIT” means The American Navigation Satellite System; (TRANSIT)
- “TRAPPAT” means Trapped Plasma Avalanche-Triggered Transit Diode; (TRAPPAT)
- “UCT” means Universal Coordinate Time; (UCT)
- “V DRM” means Repetitive Peak Off State Voltage; (V DRM)
- “VOR” means Visual Omirange; (VOR)
- «ROC» Équipement de reconnaissance optique de caractères (OCR)
- «ROM» Mémoire morte (ROM)
- «SAE» Society of Automotive Engineers (SAE)
- «TCXO» Oscillateur à quartz à compensation thermique (TCXO)
- «TDTC» Transformateur différentiel à tension linéaire (LVDT)
- «TED» Transferred Electron Device (TED)
- «TET» Transmission électromagnétique transverse (ETT)
- «TIR» Lecture d'indicateur totale (TIR)
- «TRANSIT» The American Navigation Satellite System (TRANSIT)
- «TRAPPAT» Trapped Plasma Avalanche-Triggered Transit Diode (TRAPATT)
- «TU» Temps universel (UCT)
- «UIT» Union internationale des télécommunications (ITU)
- «ULA» Unité logique arithmétique (ALU)
- «UMI» Unité de mesure d'inertie (IMU)
- «V DRM» Tension de pointe répétitive à l'état bloqué (V DRM)
- «VOR» Visuel omni-portée (VOR)